



DMT3006LFV

PowerDI3333-8 (Type UX)

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C		
30V	$7m\Omega @ V_{GS} = 10V$	60A		
30 V	$11m\Omega @ V_{GS} = 4.5V$	OOA		

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Power Management Functions
- Analog Switch

Features

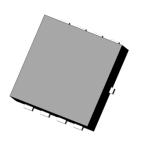
- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products

30V N-CHANNEL ENHANCEMENT MODE MOSFET

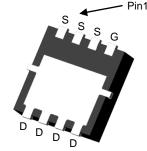
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

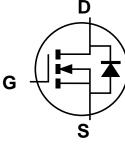
- Case: PowerDI[®]3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)



Top View



Bottom View



Equivalent Circuit

Ordering Information (Note 4)

	Part Number	Case	Packaging			
	DMT3006LFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel			
	DMT3006LFV-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel			
Notes:	Notes: 1. No purposely added lead, Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. Lead-free. Halogan and Antimony free "Green" products are defined as these which contain <2000 ppm bramine <2000 ppm chloring (<1500 ppm total Br + Cl) and

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\frac{FV6}{YY}WW = \text{Date Code Marking}$ $\frac{\overline{YY}}{\overline{YY}} = \text{Last Two Digits of Year (ex: 18 = 2018)}$ WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current, V_{GS} = 10V (Note 7)	Steady State	T _C = +25°C T _C = +70°C	ID	60 45	А
Maximum Body Diode Forward Current (Note 7)	ls	2	A		
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%	I _{DM}	90	A		
Pulsed Drain Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)			I _{SM}	90	А
Avalanche Current (L = 0.1mH) (Note 8)	I _{AS}	24	A		
Avalanche Energy (L = 0.1mH) (Note 8)			E _{AS}	29	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ ext{ heta}JA}$	130	°C/W
Total Power Dissipation (Note 6)		PD	2.0	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		$R_{ heta JA}$	63	°C/W
Thermal Resistance, Junction to Case (Note 7)	$R_{ ext{ heta}JC}$	2.9		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	T. m	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	Symbol	IVIIII	Тур	wax	Unit	Test Condition	
· · · · · · · · · · · · · · · · · · ·		30			V	1/1 = 0/1 = 0.0000	
Drain-Source Breakdown Voltage	BV _{DSS}			_	-	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}	_	_	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)						÷	
Gate Threshold Voltage	V _{GS(TH)}	1.0	_	3.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance			5.6	7	mΩ	$V_{GS} = 10V, I_D = 9.0A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	8.0	11		$V_{GS} = 4.5V, I_D = 8.5A$	
Diode Forward Voltage	V _{SD}	—	0.70	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)						÷	
Input Capacitance	C _{iss}	_	1,155	_		V_{DS} = 15V, V_{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	—	456	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	72	_			
Gate Resistance	Rg	_	1.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	8.4	_			
Total Gate Charge (V _{GS} = 10V)	Qg	_	16.7	_	nC	$V_{DD} = 15V, I_D = 9A$	
Gate-Source Charge	Qgs	_	2.2	_	nc		
Gate-Drain Charge	Q _{gd}	—	3.5	_			
Turn-On Delay Time	t _{D(ON)}	_	3.5	_			
Turn-On Rise Time	t _R	_	5.5	_		$V_{DD} = 15V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}		13.5		ns	$R_g = 3\Omega, I_D = 9A$	
Turn-Off Fall Time	tF	_	4.6		1		
Reverse Recovery Time	t _{RR}		19.3	—	ns		
Reverse Recovery Charge	Q _{RR}		8.6	_	nC	I _F = 1.5A, di/dt = 100A/μs	

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

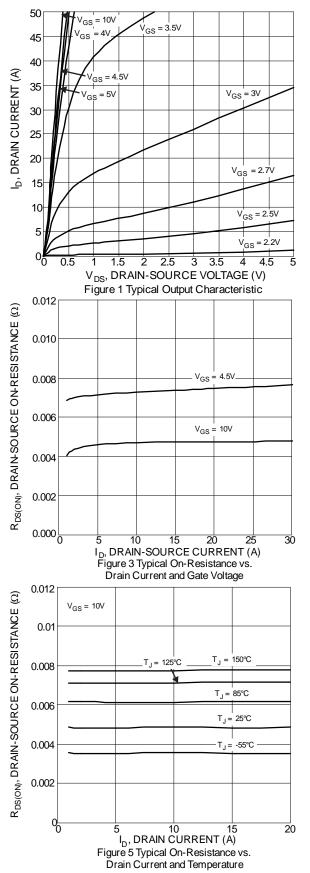
8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

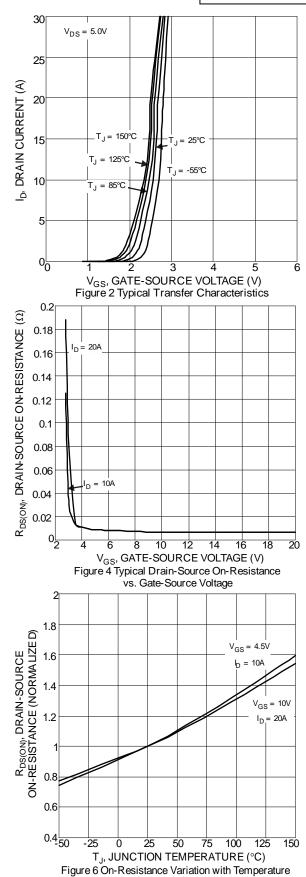
9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.

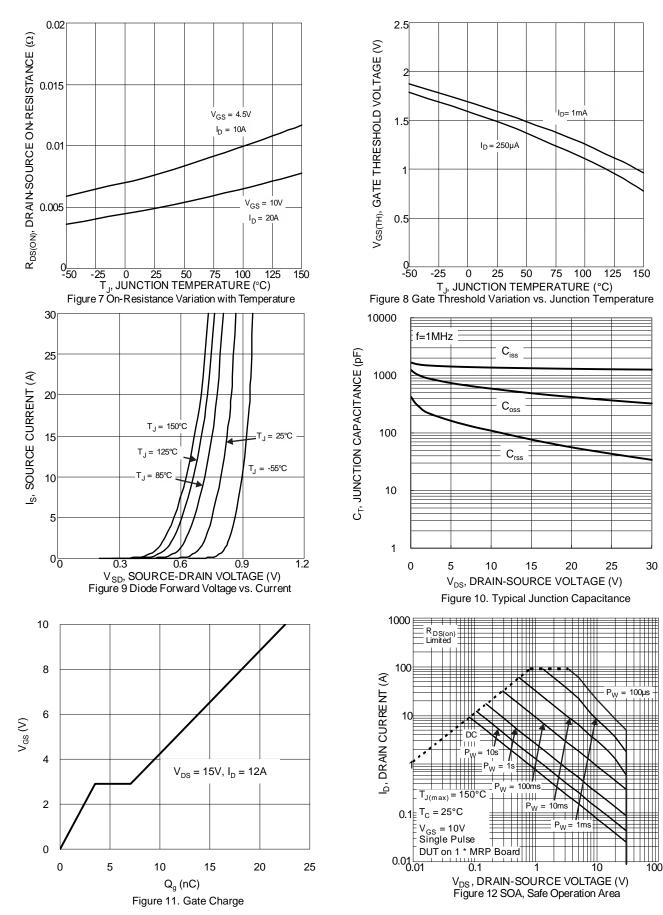




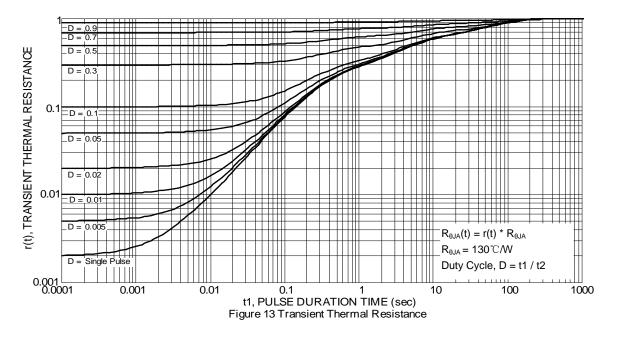










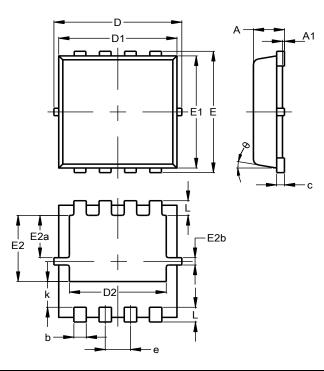




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

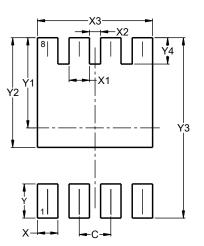


PowerDI3333-8 (Type UX)						
Dim	Min Max Ty					
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.20 3.40 3.30				
D1	2.95	2.95 3.15 3.0				
D2	2.30	2.30 2.70				
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	1.60 2.00 1.8				
E2a	0.95	0.95 1.35 1.15				
E2b	0.10 0.30 0.20					
е	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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